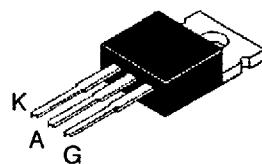


## SENSITIVE GATE SCR

### FEATURES

- $I_{T(RMS)} = 8A$
- $V_{DRM} = 200V$  to  $800V$
- Low  $I_{GT} < 200 \mu A$



**TO220  
non-insulated  
(Plastic)**

### DESCRIPTION

The S0802xH series of SCRs uses a high performance MESA GLASS PNPN technology. These parts are intended for general purpose applications where low gate sensitivity is required.

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
$I_{T(RMS)}$	RMS on-state current (180° conduction angle)	8	A
$I_{T(AV)}$	Mean on-state current (180° conduction angle)	5	A
$I_{TSM}$	Non repetitive surge peak on-state current ( $T_j$ initial = 25°C )	tp = 8.3 ms	73
		tp = 10 ms	70
$I^2t$	$I^2t$ Value for fusing	24	$A^2s$
$dI/dt$	Critical rate of rise of on-state current $I_G = 10 mA$ $dI_G/dt = 0.1 A/\mu s$ .	100	$A/\mu s$
$T_{stg}$ $T_j$	Storage and operating junction temperature range	- 40, + 150 - 40, + 125	°C
$T_I$	Maximum lead temperature for soldering during 10s at 4.5mm from case	260	°C

Symbol	Parameter	Voltage				Unit
		B	D	M	N	
$V_{DRM}$ $V_{RRM}$	Repetitive peak off-state voltage $T_j = 125^\circ C$ $R_{GK} = 1K\Omega$	200	400	600	800	V

## S0802xH

### THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R <sub>th(j-a)</sub>	Junction to ambient	60	°C/W
R <sub>th(j-c)</sub>	Junction to case for DC	4	°C/W

### GATE CHARACTERISTICS (maximum values)

P<sub>G(AV)</sub> = 0.5 W P<sub>GM</sub> = 5 W (tp = 20 μs) I<sub>GM</sub> = 2 A (tp = 20 μs)

### ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions			Sensitivity	Unit
				02	
I <sub>GT</sub>	V <sub>D</sub> =12V (DC)	R <sub>L</sub> =140Ω	T <sub>j</sub> = 25°C	MAX	200
V <sub>GT</sub>	V <sub>D</sub> =12V (DC)	R <sub>L</sub> =140Ω	T <sub>j</sub> = 25°C	MAX	1.5
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> R <sub>L</sub> =3.3kΩ R <sub>GK</sub> = 1 KΩ		T <sub>j</sub> = 125°C	MIM	0.1
V <sub>VRGM</sub>	I <sub>RG</sub> = 10μA		T <sub>j</sub> = 25°C	MIN	8
t <sub>gd</sub>	V <sub>D</sub> =V <sub>DRM</sub> I <sub>TM</sub> = 3 × I <sub>T(AV)</sub> dI <sub>G</sub> /dt = 0.1A/μs I <sub>G</sub> = 10mA		T <sub>j</sub> = 25°C	TYP	0.5
I <sub>H</sub>	I <sub>T</sub> = 50mA R <sub>GK</sub> = 1 KΩ		T <sub>j</sub> = 25°C	MAX	10
I <sub>L</sub>	I <sub>Q</sub> =1mA R <sub>GK</sub> = 1 KΩ		T <sub>j</sub> = 25°C	MAX	20
V <sub>TM</sub>	I <sub>TM</sub> = 16A tp= 380μs		T <sub>j</sub> = 25°C	MAX	1.6
I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>D</sub> = V <sub>DRM</sub> R <sub>GK</sub> = 1 KΩ		T <sub>j</sub> = 25°C	MAX	5
	V <sub>R</sub> = V <sub>RRM</sub>		T <sub>j</sub> = 110°C	MAX	500
dV/dt	V <sub>D</sub> =67%V <sub>DRM</sub> R <sub>GK</sub> = 1 KΩ		T <sub>j</sub> = 110°C	TYP	10
t <sub>q</sub>	I <sub>TM</sub> = 3 × I <sub>T(AV)</sub> V <sub>R</sub> =35V dI/dt=10A/μs tp=100μs dV/dt=2V/μs V <sub>D</sub> = 67%V <sub>DRM</sub> R <sub>GK</sub> = 1 KΩ		T <sub>j</sub> = 110°C	MAX	100

### ORDERING INFORMATION

